



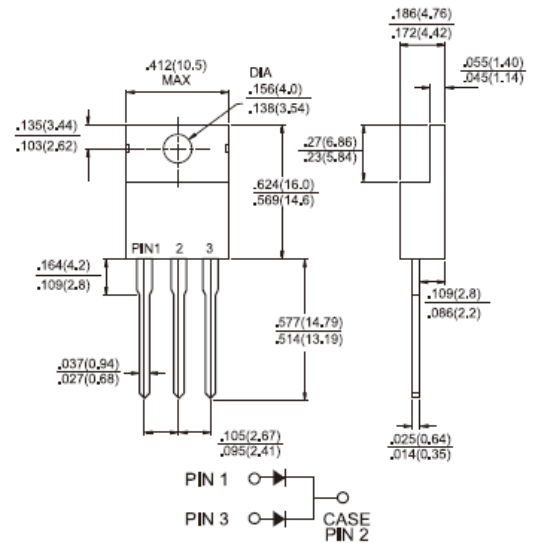
SF801G - SF808G
8.0AMPS. Glass Passivated Super Fast Rectifiers
TO-220AB

Features

- ◇ High efficiency, low VF
- ◇ High current capability
- ◇ High reliability
- ◇ High surge current capability
- ◇ Low power loss.
- ◇ For use in low voltage, high frequency inverter, free wheeling, and polarity protection application
- ◇ Green compound with suffix "G" on packing code & prefix "G" on datecode.

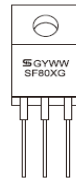
Mechanical Data

- ◇ Case: TO-220AB Molded plastic
- ◇ Epoxy: UL 94V-0 rate flame retardant
- ◇ Terminals: Pure tin plated, lead free. Solderable per MIL-STD-202, Method 208 guaranteed
- ◇ Polarity: As marked
- ◇ High temperature soldering guaranteed: 260°C/10 seconds 16".,(4.06mm) from case.
- ◇ Weight: 1.90 grams



Dimensions in inches and (millimeters)

Marking Diagram



- SF80XG = Specific Device Code
- G = Green Compound
- Y = Year
- WW = Work Week

Maximum Ratings and Electrical Characteristics

Rating at 25 °C ambient temperature unless otherwise specified.
 Single phase, half wave, 60 Hz, resistive or inductive load.
 For capacitive load, derate current by 20%

Type Number	Symbol	SF 801G	SF 802G	SF 803G	SF 804G	SF 805G	SF 806G	SF 807G	SF 808G	Units
Maximum Recurrent Peak Reverse Voltage	V_{RRM}	50	100	150	200	300	400	500	600	V
Maximum RMS Voltage	V_{RMS}	35	70	105	140	210	280	350	480	V
Maximum DC Blocking Voltage	V_{DC}	50	100	150	200	300	400	500	600	V
Maximum Average Forward Rectified Current	$I_{F(AV)}$	8								A
Peak Forward Surge Current, 8.3 ms Single Half Sine-wave Superimposed on Rated Load (JEDEC method)	I_{FSM}	125								A
Maximum Instantaneous Forward Voltage (Note 1) @ 4 A	V_F	0.975			1.3		1.7			V
Maximum DC Reverse Current @ $T_A=25\text{ }^\circ\text{C}$ at Rated DC Blocking Voltage @ $T_A=100\text{ }^\circ\text{C}$	I_R					10				uA
						400				uA
Maximum Reverse Recovery Time (Note 2)	T_{rr}					35				nS
Typical Junction Capacitance (Note 3)	C_j	70			50					pF
Typical Thermal Resistance	$R_{\theta JC}$					3.0				$^\circ\text{C/W}$
Operating Temperature Range T_J	T_J					- 65 to + 150				$^\circ\text{C}$
Storage Temperature Range T_{STG}	T_{STG}					- 65 to + 150				$^\circ\text{C}$

Note 1: Pulse Test with PW=300 usec, 1% Duty Cycle
 Note 2: Reverse Recovery Test Conditions: $I_F=0.5A$, $I_R=1.0A$, $I_{RR}=0.25A$.
 Note 3: Measured at 1 MHz and Applied Reverse Voltage of 4.0 V D.C.

RATINGS AND CHARACTERISTIC CURVES (SF801G THRU SF808G)

FIG. 1- MAXIMUM FORWARD CURRENT DERATING CURVE

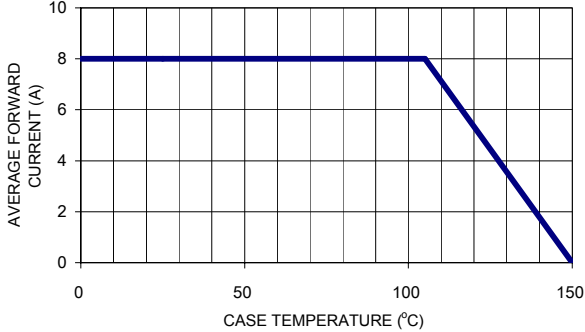


FIG. 2- TYPICAL REVERSE CHARACTERISTICS

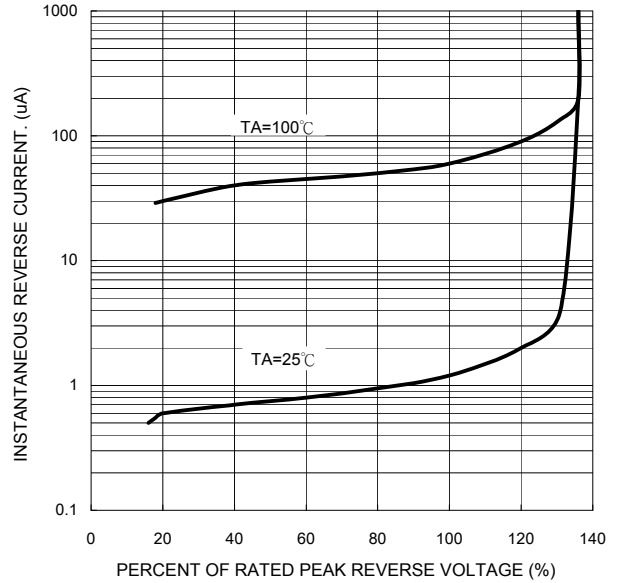


FIG. 3- MAXIMUM NON-REPETITIVE FORWARD SURGE CURRENT

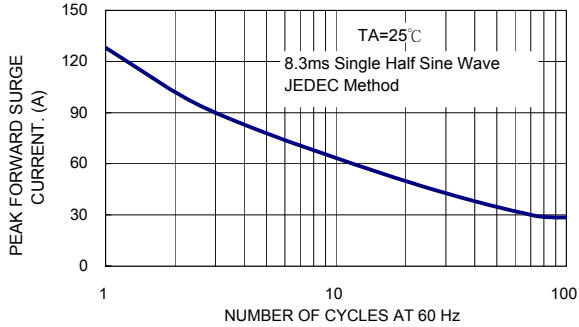


FIG. 5- TYPICAL FORWARD CHARACTERISTICS

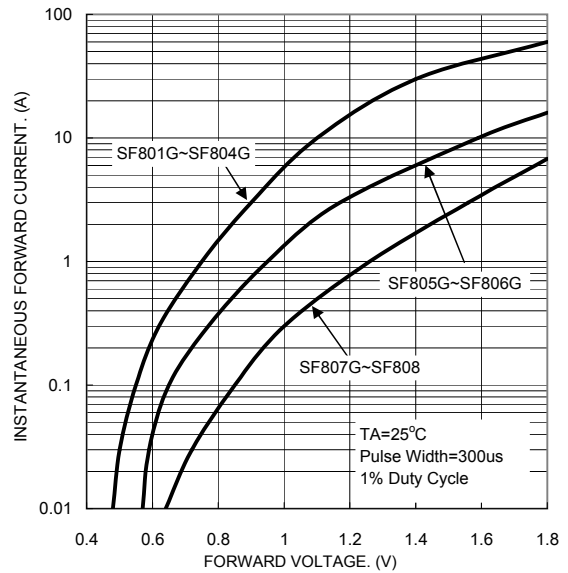


FIG. 4- TYPICAL JUNCTION CAPACITANCE

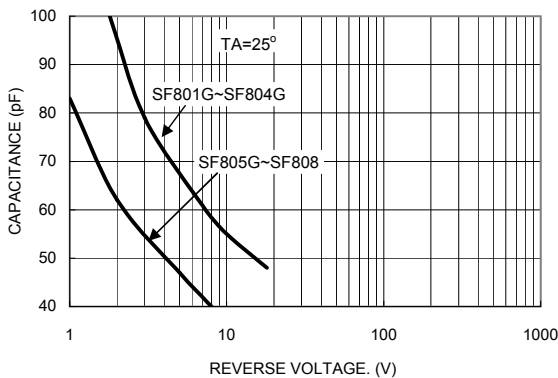
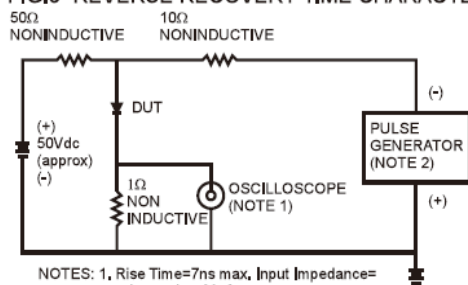


FIG. 6- REVERSE RECOVERY TIME CHARACTERISTIC AND TEST CIRCUIT DIAGRAM



NOTES: 1. Rise Time=7ns max, Input Impedance=1 megohm 22pf
2. Rise Time=10ns max. Source Impedance=50 ohms

